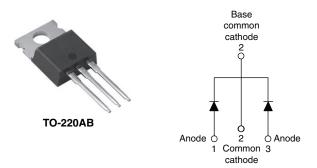


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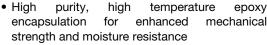
Schottky Rectifier, 2 x 30 A

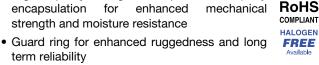


PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 30 A			
V_{R}	100 V			
V _F at I _F	0.69 V			
I _{RM} max.	20 mA at 125 °C			
T_J max.	175 °C			
Diode variation	Common cathode			
E _{AS}	11.25 mJ			

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation





- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform (per device)	60	A	
V _{RRM}		100	V	
I _{FRM}	T _C = 139 °C (per leg)	60	Α	
I _{FSM}	t _p = 5 μs sine	1500		
V _F	30 A _{pk} , T _J = 125 °C	0.69	V	
T _J	Range	- 65 to 175	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-63CTQ100PbF	VS-63CTQ100-N3	UNITS
Maximum DC reverse voltage	V _R	100	100	V
Maximum working peak reverse voltage	V _{RWM}	100	100	V

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per leg		50 % duty cycle at T _C = 139 °C, rectangular waveform		30	
forward current	per device	I _{F(AV)}			60	
Peak repetitive forward curre	nt per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 140 °C		60	Α
Maximum peak one cycle non-repetitive surge current per leg		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500	
			10 ms sine or 6 ms rect. pulse	V _{RRM} applied	300	
Non-repetitive avalanche ene	ergy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.75 A, L = 40 mH		11.25	mJ
Repetitive avalanche current	per leg	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.75	Α



VS-63CTQ100PbF, VS-63CTQ100-N3

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
	V _{FM} ⁽¹⁾	30 A	T _J = 25 °C	0.78	0.82	V
Maximum forward voltage drop		60 A		0.94	1.0	
		30 A	- T _J = 125 °C	0.64	0.69	
		60 A		0.78	0.83	
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.02	0.3	mA
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	11	20	IIIA
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		11	00	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8	.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65 to 175	°C	
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.2	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	C/W	
Approximate weight			2	g	
Approximate weight			0.07	OZ.	
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm	
maximum		Non-iublicated tilleads	12 (10)	(lbf \cdot in)	
Marking device		Case style TO-220AB	63CT	Q100	

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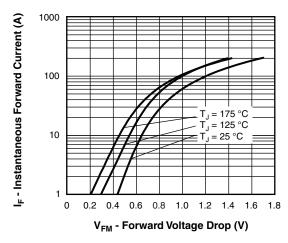


Fig. 1 - Maximum Forward Voltage Drop Characteristics

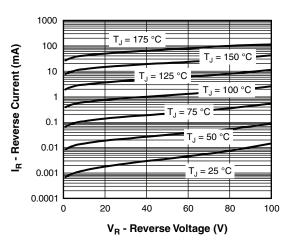


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

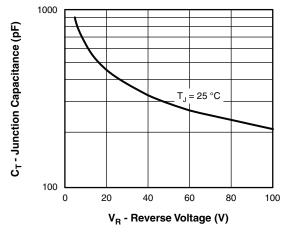


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

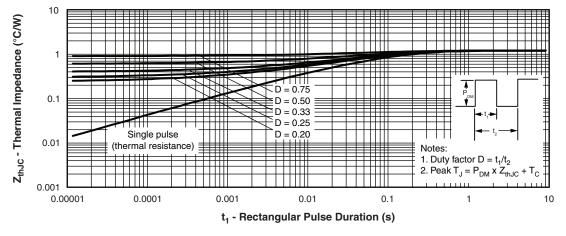


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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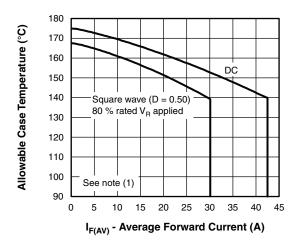


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

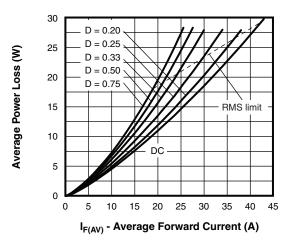


Fig. 6 - Forward Power Loss Characteristics

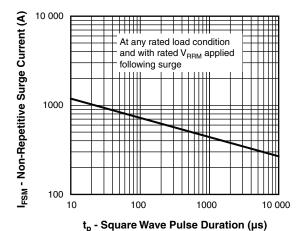


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

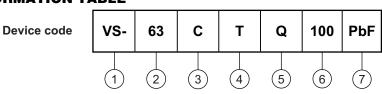
Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

VS-63CTQ100PbF, VS-63CTQ100-N3

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ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Current rating (60 A)

3 - Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

Voltage rating (100 = 100 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-63CTQ100PbF	50	1000	Antistatic plastic tube		
VS-63CTQ100-N3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95222			
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000